# P-Channel 200-V (D-S) MOSFET

### **Key Features:**

- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

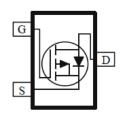
### **Typical Applications:**

- PoE Power Sourcing Equipment
- PoE Powered Devices
- Telecom DC/DC converters
- · White LED boost converters

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)}(\Omega)$	I <sub>D</sub> (A)	
-200	$2.5 @ V_{GS} = -10V$	-0.6	
	$2.8 @ V_{GS} = -5.5V$	-0.5	







ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Drain-Source Voltage		V <sub>DS</sub>	-200	V	
Gate-Source Voltage		$V_{GS}$	±20	V	
Continuous Dusin Commenta	T <sub>A</sub> =25°		-0.6		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =70°	C ID	-0.5	Α	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	5		
Continuous Source Current (Diode Conduction) a		I <sub>S</sub>	1.2	Α	
Dower Discination <sup>a</sup>	T <sub>A</sub> =25°		1.3	W	
Power Dissipation <sup>a</sup>	T <sub>A</sub> =70°	C	0.8	V V	
Operating Junction and Storage Temperature Range		$T_J, T_{sta}$	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
Maximum Junction-to-Ambient <sup>a</sup>	t <= 10 sec	$R_{\theta JA}$	100	°C/W		
Maximum Junction-to-Ambient	Steady State		166			

#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

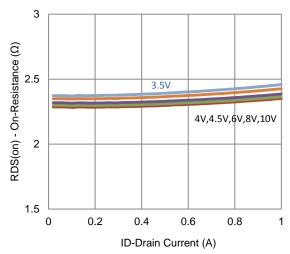
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-1			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zoro Coto Voltago Droin Current	1	$V_{DS} = -160 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -160 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-10		
On-State Drain Current	I <sub>D(on)</sub>	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-0.5			Α	
Drain Cauras On Basistana	r	$V_{GS} = -10 \text{ V}, I_{D} = -0.5 \text{ A}$			2.5	Ω	
Drain-Source On-Resistance	r <sub>DS(on)</sub>	$V_{GS} = -5.5 \text{ V}, I_D = -0.4 \text{ A}$			2.8		
Forward Transconductance	g <sub>fs</sub>	$V_{DS} = -15 \text{ V}, I_{D} = -0.5 \text{ A}$		1.8		S	
Diode Forward Voltage	$V_{SD}$	$I_S = -0.6 \text{ A}, V_{GS} = 0 \text{ V}$		-0.87		V	
		Dynamic					
Total Gate Charge	$Q_g$	$V_{DS} = -100 \text{ V}, V_{GS} = -5.5 \text{ V},$		3.7		nC	
Gate-Source Charge	$Q_{gs}$	$I_{DS} = -100 \text{ V}, \text{ V}_{GS} = -5.5 \text{ V},$ $I_{D} = -0.5 \text{A}$		1.1			
Gate-Drain Charge	$Q_{gd}$	ID = -0.5A		1.5			
Turn-On Delay Time	t <sub>d(on)</sub>	V - 100 V B - 200 O		4		ns	
Rise Time	t <sub>r</sub>	$V_{DD}$ = -100 V, $R_L$ = 200 Ω, $I_D$ = -0.5A, $V_{GEN}$ = -10 V, $R_{GEN}$ = 6 Ω		10			
Turn-Off Delay Time	$t_{d(off)}$			13			
Fall-Time	t <sub>f</sub>	v GEN - 10 v, 1 (GEN - 0 12		10			
Input Capacitance	C <sub>iss</sub>			301			
Output Capacitance	C <sub>oss</sub>	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		39		pF	
Reverse Transfer Capacitance	$C_{rss}$			21			

#### **Notes**

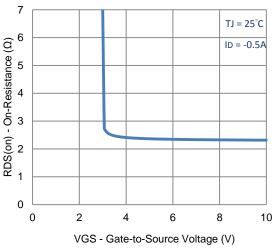
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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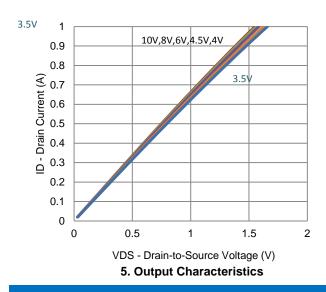
### **Typical Electrical Characteristics**

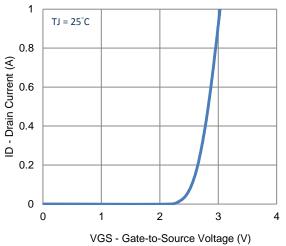


#### 1. On-Resistance vs. Drain Current

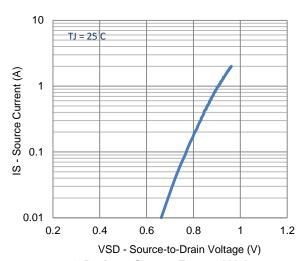


3. On-Resistance vs. Gate-to-Source Voltage

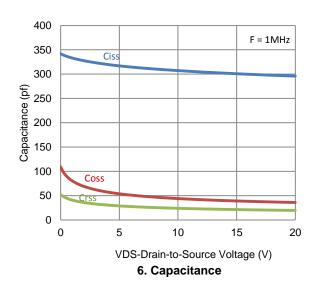




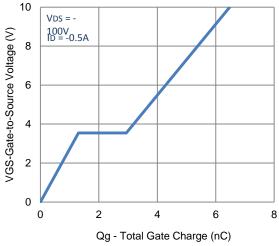
2. Transfer Characteristics

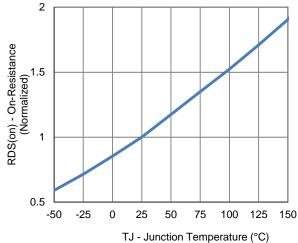


4. Drain-to-Source Forward Voltage



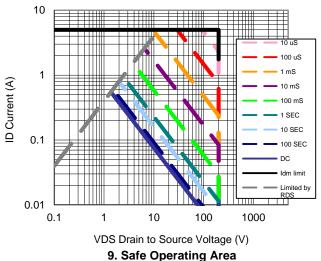
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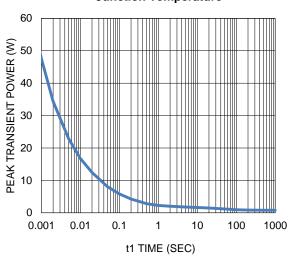




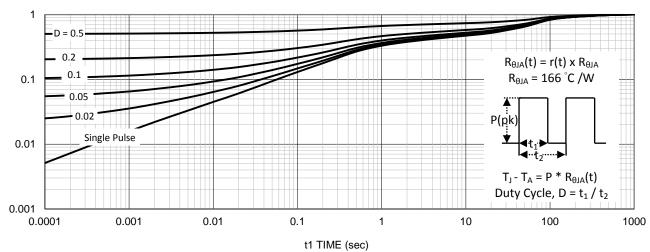
7. Gate Charge

8. Normalized On-Resistance Vs
Junction Temperature



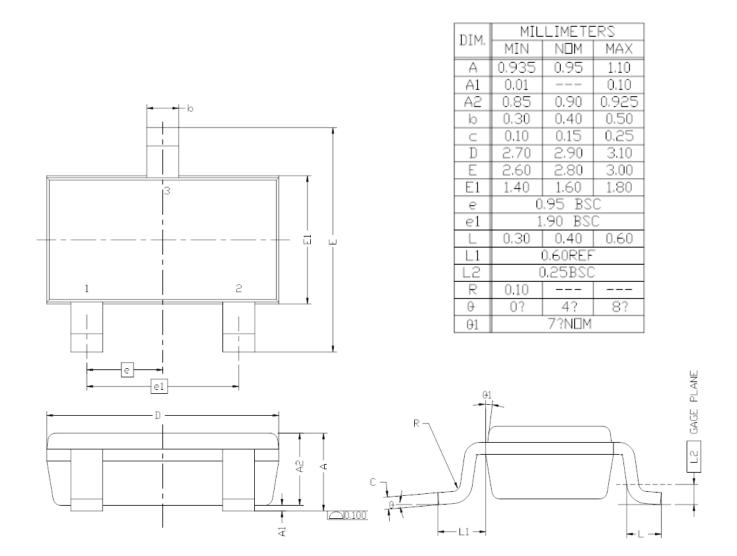


10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

### **Package Information**



#### Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- 5. Dimension B" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess Of B" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The Foot.